Amplifier Transistors

NPN Silicon

Features

• These are Pb-Free Devices*

MAXIMUM RATINGS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	40	Vdc
Collector – Base Voltage	V _{CBO}	75	Vdc
Emitter-Base Voltage	V _{EBO}	6.0	Vdc
Collector Current – Continuous	Ι _C	600	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0	mW mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C	PD	1.5 12	W mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	–55 to +150	°C

THERMAL CHARACTERISTICS

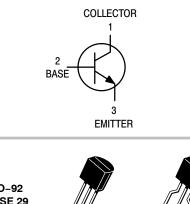
Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W

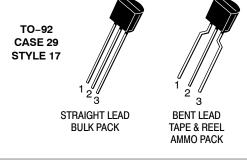
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



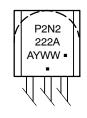
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MARKING DIAGRAM



= Assembly Location

= Year

А

γ

WW = Work Week

= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
P2N2222AG	TO-92 (Pb-Free)	5000 Units/Bulk
P2N2222ARL1G	TO-92 (Pb-Free)	2000/Tape & Ammo

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

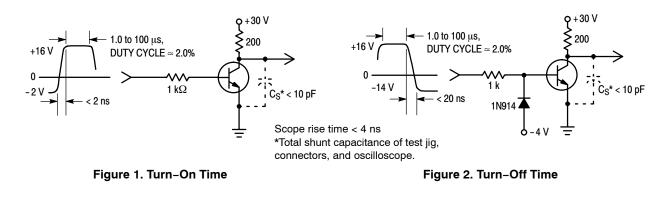
ELECTRICAL CHARACTERISTICS (T_A = $25^{\circ}C$ unless otherwise noted)

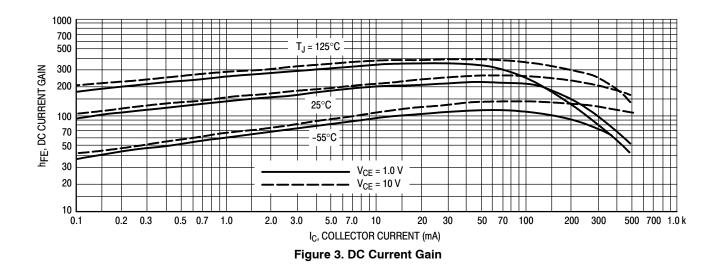
Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector – Emitter Breakdown Voltage $(I_C = 10 \text{ mAdc}, I_B = 0)$	V _{(BR)CEO}	40	-	Vdc
Collector – Base Breakdown Voltage (I _C = 10 μAdc, I _E = 0)	V _{(BR)CBO}	75	-	Vdc
Emitter – Base Breakdown Voltage $(I_E = 10 \ \mu Adc, I_C = 0)$	V _{(BR)EBO}	6.0	_	Vdc
Collector Cutoff Current (V _{CE} = 60 Vdc, V _{EB(off)} = 3.0 Vdc)	ICEX	_	10	nAdc
Collector Cutoff Current $(V_{CB} = 60 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 60 \text{ Vdc}, I_E = 0, T_A = 150^{\circ}\text{C})$	I _{CBO}		0.01 10	μAdc
Emitter Cutoff Current (V _{EB} = 3.0 Vdc, I _C = 0)	I _{EBO}	_	10	nAdc
Collector Cutoff Current (V _{CE} = 10 V)	I _{CEO}	_	10	nAdc
Base Cutoff Current (V _{CE} = 60 Vdc, V _{EB(off)} = 3.0 Vdc)	I _{BEX}	_	20	nAdc
ON CHARACTERISTICS				
$ \begin{array}{l} \text{DC Current Gain} \\ (I_{C}=0.1 \text{ mAdc}, V_{CE}=10 \text{ Vdc}) \\ (I_{C}=1.0 \text{ mAdc}, V_{CE}=10 \text{ Vdc}) \\ (I_{C}=10 \text{ mAdc}, V_{CE}=10 \text{ Vdc}) \\ (I_{C}=10 \text{ mAdc}, V_{CE}=10 \text{ Vdc}, T_{A}=-55^{\circ}\text{C}) \\ (I_{C}=150 \text{ mAdc}, V_{CE}=10 \text{ Vdc}) (\text{Note 1}) \\ (I_{C}=150 \text{ mAdc}, V_{CE}=1.0 \text{ Vdc}) (\text{Note 1}) \\ (I_{C}=500 \text{ mAdc}, V_{CE}=10 \text{ Vdc}) (\text{Note 1}) \\ (I_{C}=500 \text{ mAdc}, V_{CE}=10 \text{ Vdc}) (\text{Note 1}) \end{array} $	h _{FE}	35 50 75 35 100 50 40	_ _ _ 300 _	-
Collector – Emitter Saturation Voltage (Note 1) ($I_C = 150 \text{ mAdc}, I_B = 15 \text{ mAdc})$ ($I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc})$	V _{CE(sat)}		0.3 1.0	Vdc
Base – Emitter Saturation Voltage (Note 1) ($I_C = 150 \text{ mAdc}, I_B = 15 \text{ mAdc}$) ($I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc}$)	V _{BE(sat)}	0.6	1.2 2.0	Vdc
SMALL-SIGNAL CHARACTERISTICS				
Current – Gain – Bandwidth Product (Note 2) (I _C = 20 mAdc, V _{CE} = 20 Vdc, f = 100 MHz)C	f _T	300	_	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 1.0 MHz)	C _{obo}	_	8.0	pF
Input Capacitance (V _{EB} = 0.5 Vdc, I _C = 0, f = 1.0 MHz)	C _{ibo}	_	25	pF
Input Impedance ($I_{C} = 1.0 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}$) ($I_{C} = 10 \text{ mAdc}, V_{CE} = 10 \text{ Vdc}, f = 1.0 \text{ kHz}$)	h _{ie}	2.0 0.25	8.0 1.25	kΩ
Voltage Feedback Ratio (I _C = 1.0 mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz) (I _C = 10 mAdc, V _{CE} = 10 Vdc, f = 1.0 kHz)	h _{re}		8.0 4.0	X 10 ⁻⁴
$ \begin{array}{l} \text{Small-Signal Current Gain} \\ (I_{C} = 1.0 \text{ mAdc}, \text{V}_{CE} = 10 \text{ Vdc}, \text{f} = 1.0 \text{ kHz}) \\ (I_{C} = 10 \text{ mAdc}, \text{V}_{CE} = 10 \text{ Vdc}, \text{f} = 1.0 \text{ kHz}) \end{array} $	h _{fe}	50 75	300 375	-
Output Admittance ($I_C = 1.0 \text{ mAdc}$, $V_{CE} = 10 \text{ Vdc}$, f = 1.0 kHz) ($I_C = 10 \text{ mAdc}$, $V_{CE} = 10 \text{ Vdc}$, f = 1.0 kHz)	h _{oe}	5.0 25	35 200	μMhos
Collector Base Time Constant (I _E = 20 mAdc, V _{CB} = 20 Vdc, f = 31.8 MHz)	rb′C _c	_	150	ps
Noise Figure (I _C = 100 μAdc, V _{CE} = 10 Vdc, R _S = 1.0 kΩ, f = 1.0 kHz)	N _F	-	4.0	dB

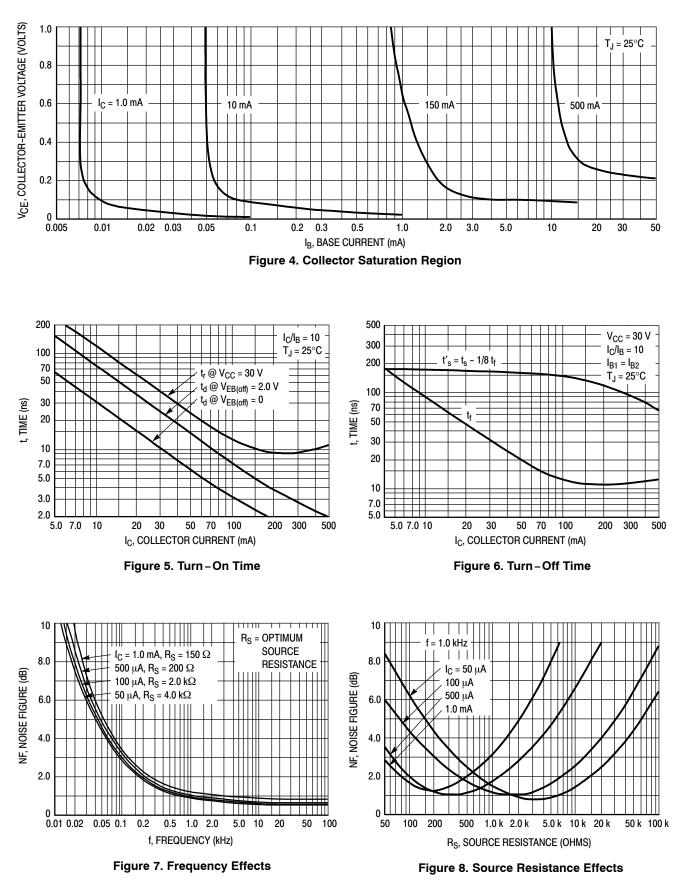
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (Continued)

	Characteristic		Min	Max	Unit
SWITCHING CHARA	SWITCHING CHARACTERISTICS				
Delay Time	(V _{CC} = 30 Vdc, V _{BE(off)} = -2.0 Vdc,	t _d	-	10	ns
Rise Time	$I_C = 150 \text{ mAdc}, I_{B1} = 15 \text{ mAdc}) \text{ (Figure 1)}$	t _r	-	25	ns
Storage Time	$(V_{CC} = 30 \text{ Vdc}, I_C = 150 \text{ mAdc},$	t _s	-	225	ns
Fall Time	$I_{B1} = I_{B2} = 15 \text{ mAdc}$ (Figure 2)	t _f	-	60	ns

SWITCHING TIME EQUIVALENT TEST CIRCUITS







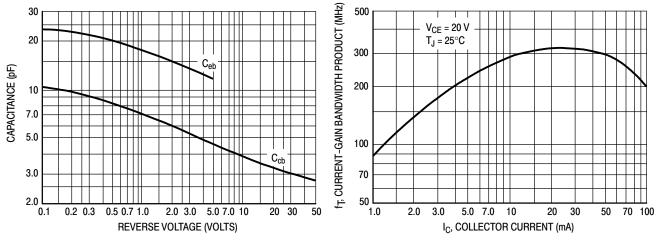


Figure 9. Capacitances

Figure 10. Current-Gain Bandwidth Product

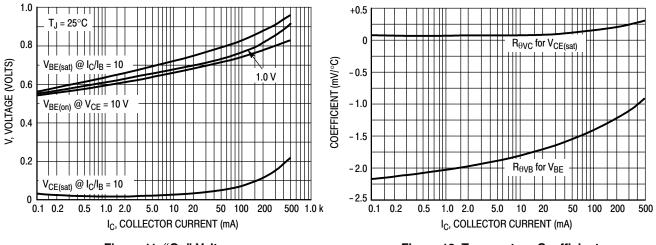


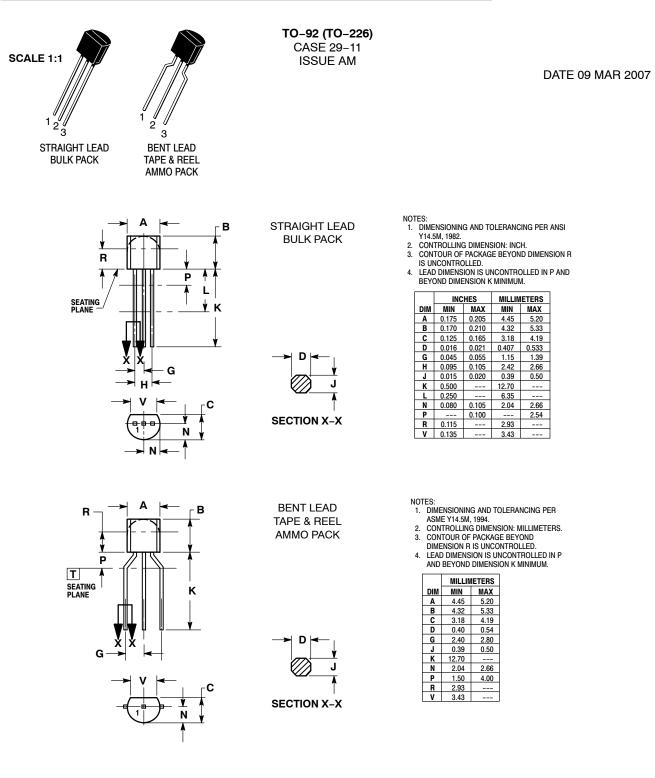
Figure 11. "On" Voltages

Figure 12. Temperature Coefficients

MECHANICAL CASE OUTLINE PACKAGE DIMENSIONS

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STYLES ON PAGE 2

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TO-92 (TO-226) CASE 29-11 ISSUE AM

DATE 09 MAR 2007

STYLE 1: PIN 1. EMITTER 2. BASE 3. COLLECTOR STYLE 6: PIN 1. GATE 2. SOURCE & SUBSTRATE 3. DRAIN STYLE 11: PIN 1. ANODE 2. CATHODE & ANODE 3. CATHODE STYLE 16: PIN 1. ANODE 2. GATE 3. CATHODE STYLE 21: PIN 1. COLLECTOR 2. EMITTER 3. BASE STYLE 22: PIN 1. VCC 2. GROUND 2 3. OUTPUT STYLE 31: PIN 1. GATE 2. DRAIN 3. SOURCE

	BASE EMITTER COLLECTOR
2.	SOURCE DRAIN GATE
2.	MAIN TERMINAL 1 Gate Main Terminal 2
2.	COLLECTOR BASE EMITTER
2.	SOURCE GATE DRAIN

2	1.	ANODE ANODE CATHODE
2	1. 2.	DRAIN Gate Source & Substrate
2	1. 2.	ANODE 1 GATE CATHODE 2
2	1. 2.	ANODE CATHODE NOT CONNECTED
2	1. 2.	GATE SOURCE DRAIN
2	1. 2.	CATHODE ANODE GATE

STYLE 33: PIN 1. RETURN 2. INPUT 3. OUTPUT

2.	CATHODE CATHODE ANODE
2.	BASE 1 EMITTER BASE 2
2.	EMITTER COLLECTOR BASE
	GATE ANODE CATHODE
2.	EMITTER Collector/Anode Cathode
2.	NOT CONNECTED ANODE CATHODE
2.	INPUT GROUND LOGIC

STYLE 4:

STYLE 5: PIN 1. DRAIN 2. SOURCE 3. GATE STYLE 10: PIN 1. CATHODE 2. GATE 3. ANODE STYLE 15: PIN 1. ANODE 1 2. CATHODE 3. ANODE 2 STYLE 20: PIN 1. NOT CONNECTED 2. CATHODE 3. ANODE STYLE 25: PIN 1. MT 1 2. GATE 3. MT 2 STYLE 30: PIN 1. DRAIN 2. GATE 3. SOURCE STYLE 35: PIN 1. DRAIN 2. GATE 3. SOURCE STYLE 35: PIN 1. GATE 2. COLLECTOR 3. EMITTER

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